

Using a balanced configuration with two single-ended transconductances reduces ACM at low frequency to the order of unity. This approach adds more load to the driving stage due to the connection two input transistors, thus doubling the input capacitance. The same also applies to the case of the common-mode feed forward (CMFF) technique. A common-mode gain, at low frequency, is given by [14]:

$$A_{CM} = \frac{v_{ocm}}{v_{icm}} = \frac{g_{m1}}{g_{m2} + g_{ds1} + g_{ds2}} \cong \frac{g_{m1}}{g_{m2}} \quad (1)$$

The operation of pseudo-OTA consists of one differential pair consisting of NMOS transistors M_1 and M_2 . MOS transistors M_3 and M_4 provide the DC bias. The pseudo-OTA characterized by performance such as high DC voltage gain, wide gain bandwidth product, low noise and consumption power [15]. The gain of the pseudo-OTA is given by:

$$V_o/V_{in} = G_{m1}R_o \quad (2)$$

and the gain bandwidth product is given by:

$$GBW = G_{m1}/C_L \quad (3)$$

where G_{m1} is the transconductance of transistor M_1 and R_o (output resistance) = $(R_o \text{ looking into the drain of } M_3)/(R \text{ looking into transistor into the drain of } M_4)$. After applying the design strategy clarified previously, the design parameters in strong inversion region, the gate-dimensions, and biasing currents, of MOS transistors are summarized in Table I.

TABLE I
 GATE DIMENSIONS AND BIASING CURRENTS OF MOS TRANSISTORS OF PROPOSED CMOS CFOA

Transistors no.	Gate dimensions and biasing currents		
	W(μm)	L(μm)	Biasing Current(μA)
M_1	12.0	0.18	25
M_2	16.1	0.18	25
M_4	11.59	0.18	50
M_3	6.21	0.18	50
M_6	9.5	0.35	50
M_5	2.0	0.18	50
M_7	23.8	0.18	50
M_8	6.0	0.18	50

In our proposed CFOA using feedback technique of pseudo-OTA by connecting the positive output terminal to the negative input terminal as shown in block diagram of Fig. 2. This technique called current feedback OTA technique [16]. This approach represents input stage of proposed CFOA and cascading with buffer stage as shown in the schematic circuit of Fig. 3.

III. SIMULATION RESULTS

A new alternative CMOS CFOA with the high-performance operation, very low input offset voltage, and low distortion are

proposed in this paper. Since, the high-frequency parameters such as voltage gain, (-3dB) bandwidth, slew rate (SR), settling time (ts) and gain bandwidth product (GBW) are improved. Fig. 3 clarifies the improvement in the open loop voltage gain and gain bandwidth product (GBW) of the proposed CMOS CFOA. Also, the magnitude curve in Fig. 4 shows the frequency response (variation of frequency against the voltage gain and phase curve shows the variation of frequency against the phase shift between input and output voltage.

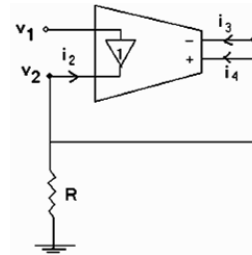


Fig. 2 Block Diagram of current feedback pseudo-OTA

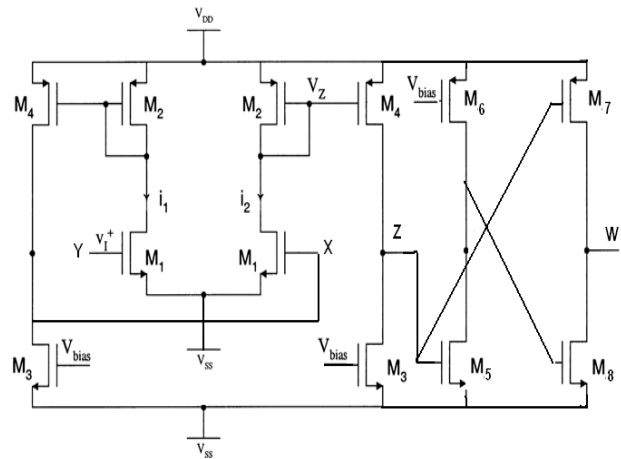


Fig. 3 Schematic circuit of proposed CFOA based on pseudo-OTA

The value of output impedance of buffer stage is decreased drastically due to using cross-coupled buffer stage. Fig. 5 indicate that the improvement in closed loop (-dB bandwidth) of the proposed CMOS CFOA, since the values of (-dB bandwidth) is 108 MHz compared with 46.2MHz with introduce the closed loop resistors are $R_F=1K\Omega$ and $R_I=1K\Omega$. The value of voltage gain will increase with decreasing in the (-3db) bandwidth due to change the value of R_I and keep the value of R_F is constant. The slow rate of CMOS and CFOA are measured from Fig. 6. DC characteristics of CMOS CFOA is shown in Fig. 7, we note that there is a large enhancement in linearity of DC characteristics of the CMOS CFOA due to the symmetry in the operation of the fully differential input stage of the pseudo-CFA OTA. Moreover, we note that the value of input offset voltage is -0.1mV due to the symmetry in the input stage (inverting and non-inverting inputs) of the proposed CMOS CFOA. Table II shows the effect of varies input resistors R_I value on the feedback loop gain and CMOS CFOA, closed loop voltage gain (A_v), gain bandwidth product

(GBW), (-3dB) bandwidth, phase margin(PM), and total harmonic distortion(HD). Simulation results of proposed CMOS CFOA confirmed the theoretical concepts in previous sections.

TABLE II
 PERFORMANCE PARAMETERS OF THE PROPOSED CMOS CFOA AS INPUT RESISTOR (R_I) IS VARIED

R_I K Ω	-3dB B.W MHz	GBW MHz	PM deg.	THD dB	A_v dB
1	79.6	108	49.9°	-67.0	5.9
0.3	32.7	89.2	48.6°	-65.0	12.5
0.1	10.7	81.8	46.0°	-41.7	20.4
0.01	1.0	78.6	45.0°	-41.0	39.1

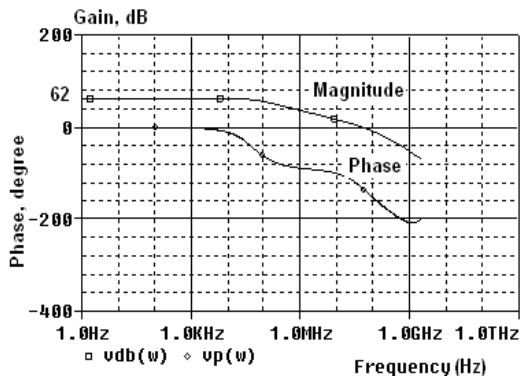


Fig. 4 Open-loop frequency response of the proposed CMOS CFOA

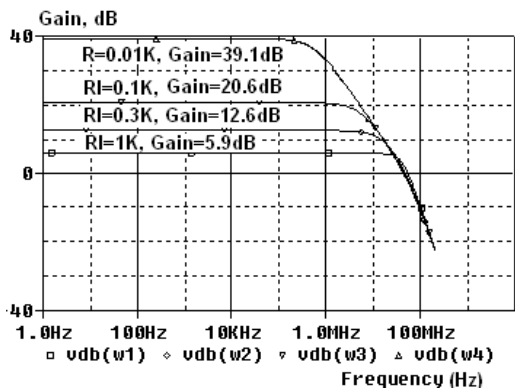


Fig. 5 Closed-loop frequency response of the proposed CMOS CFOA as R_I is varied from 0.01K Ω to 1 K Ω

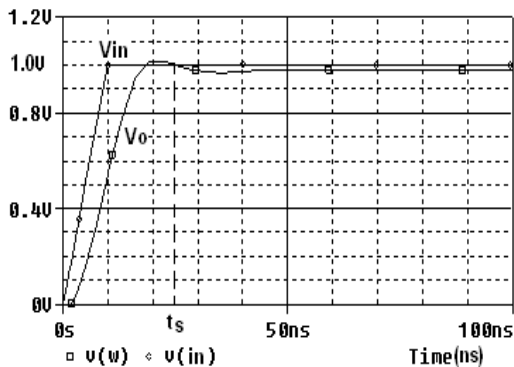


Fig. 6 Transient response of the proposed CMOS CFOA

TABLE III
 SUMMARIZED PERFORMANCE PARAMETERS OF THE PROPOSED CMOS AND CFOA

Parameters	CMOS CFOA
Supply voltage	± 1.2
Biassing current	50 μ A
Open loop gain @ $R_I=10K\Omega$, $C_L=10p$	62.0dB
Open loop (GBW) at $R_L=10K\Omega$, $C_L=10pF$	108MHz
Compensation capacitor (C_c)	0.5pF
Phase Margin (PM)	53°
Trans impedance gain at node (Z)	156dB
Closed loop (GBW) @ $R_f = 1K\Omega$, $R_i = 1K\Omega$	46.2MHz
Phase Margin (PM)	80°
Slew rate @ $C_L=10p$	+71.2 V/ μ S, -61V/ μ S
Settling time@ $C_L=10p$	46.0 ns
Total harmonic distortion(THD)	-63.0 dB
Input offset voltage @ $V_{in}=0V$	-0.1mV, 0.15 mV
Consumption power	2.0 mW
Die area	0.052 mm ²

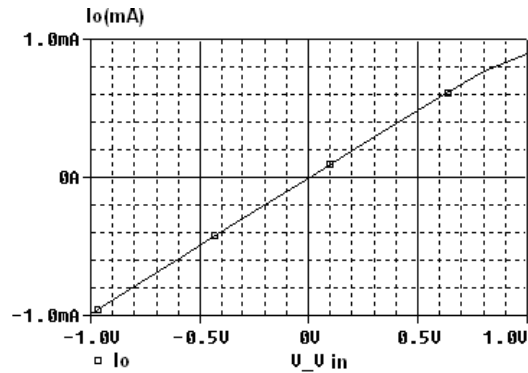


Fig. 7 DC characteristics of the proposed CMOS CFOA

IV. CONCLUSION

A new design technique of the CMOS CFOA with attractive features for high frequency, low offset voltage, and low distortion is proposed in this paper. The proposed design based on cross-coupled buffer stage that connected as the output stage of the CMOS CFOA. Since this technique operates on logic transition concept that gives the high speed, symmetry operation of the output signal and high current drive capability of proposed CMO CFOA. The high speed operation improved high performance parameters such as gain bandwidth (GBW), (-3dB) bandwidth, slew rate (SR) and settling time (t_s) with ensure the phase margin (PM) in acceptable value that keep the stability of operation. Moreover, the symmetry of input differential of pseudo-CFA OTA technique decreased the distortion in the output signal and improved (DC) characteristics of CMOS CFOA. Also to that using pseudo-OTA as the input stage of CMOS CFOA make the symmetry of inverting and non-inverting inputs that reduce input offset voltage. The trans-impedance node (Z) of the CMOS CFOA gained high value due to cascading transistors of CFA OTA. This feature is very important for design CMOS CFOA with high gain. We can summarize our conclusion by saying that the proposed CMOS CFOA with

symmetry of the input stage and symmetry of the output stage will gain CMOS CFOA attractive features for many high frequencies, low distortion, low input offset voltage applications. Also, the CMFB circuit is avoided due to the connection of the output terminal of the pseudo-OTA to input terminal to propose current feedback OTA.

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